

Vishay Telefunken

Fast Infrared Transceiver Module Family (FIR, 4 Mbit/s) for 2.6 V to 5.5 V Operation



Description

The TFDU6101E, TFDS6401, TFDS6501E, TFDT6501E are a family of low–power infrared transceiver modules compliant to the IrDA standard for fast infrared data communication, supporting IrDA speeds up to 4.0 Mbit/s (FIR), HP-SIR, Sharp ASK and carrier based remote control modes up to 2 MHz. Integrated within the transceiver modules are a photo PIN diode, an infrared emitter (IRED), and a low–power CMOS control IC to provide a total front—end solution in a single package.

Vishay Telefunken's FIR transceivers are available in four package options, including our Baby Face package (TFDU610xE), the standard setting, once

smallest FIR transceiver available on the market. This wide selection provides flexibility for a variety of applications and space constraints. The transceivers are capable of directly interfacing with a wide variety of I/O devices which perform the modulation/ demodulation function, including National Semiconductor's PC87338, PC87108 and PC87109, SMC's FDC37C669, FDC37N769 and CAM35C44, and Hitachi's SH3. At a minimum, a current-limiting resistor in series with the infrared emitter and a V_{CC} bypass capacitor are the only external components required implementing a complete solution.

Features

- Compliant to the IrDA physical layer standard (Up to 4 Mbit/s), HP-SIR[®], Sharp ASK[®] and TV Remote Control
- For 3.0 V and 5.0 V Applications
- Operates from 2.6 V to 5.5 V within specification, operational down to 2.4 V
- Low Power Consumption (3 mA Supply Current)
- Power Shutdown Mode (1 μA Shutdown Current)
- Four Surface Mount Package Options
 - Universal $(9.7 \times 4.7 \times 4.0 \text{ mm})$
 - Side View (13.0 \times 5.95 \times 5.3 mm)
 - Top View (13.0 \times 7.6 \times 5.95 mm)
 - Dracula $(11.2 \times 5.6 \times 2.2 \text{ mm})$
- Push-Pull-Receiver Output, grounded in shutdown mode

Applications

- Notebook Computers, Desktop PCs, Palmtop Computers (Win CE, Palm PC), PDAs
- Digital Still and Video Cameras
- Printers, Fax Machines, Photocopiers, Screen Projectors

- High Efficiency Emitter
- Baby Face (Universal) Package Capable of Surface Mount Soldering to Side and Top View Orientation
- Directly Interfaces with Various Super I/O and Controller Devices
- Built-In EMI Protection No External Shielding Necessary
- Few External Components Required
- Backward Pin to Pin Compatible to all Vishay Telefunken SIR and FIR Infrared Transceivers
- Split power supply, transmitter and receiver can be operated from two power supplies with relaxed requirements, thus saving costs
- Telecommunication Products (Cellular Phones, Pagers)
- Internet TV Boxes, Video Conferencing Systems
- External Infrared Adapters (Dongles)
- Medical and Industrial Data Collection Devices

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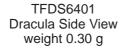
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Package Options

TFDU6101E Baby Face (Universal) weight 0.20 g







TFDS6501E Side View weight 0.39 g



TFDT6501E Top View weight 0.39 g



Ordering Information

Part Number	Qty / Reel	Description
TFDU6101E-TR4	1000 pcs	Oriented in carrier tape for side view surface mounting
TFDU6101E-TT4	1000 pcs	Oriented in carrier tape for top view surface mounting
TFDS6401-TR3	1000 pcs	Side View
TFDS6501E-TR4	750 pcs	Side View
TFDT6501E-TR4	750 pcs	Top View

Functional Block Diagram

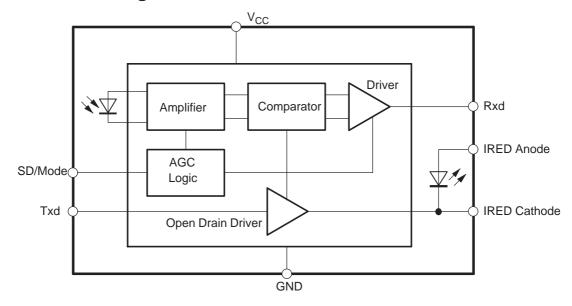


Figure 1. Functional Block Diagram

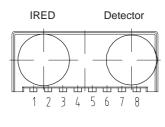


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Pin Description

Pin Number		Function	Description	I/O	Active
"U" and "T" Option	"S" Option				
1	8	IRED Anode	IRED anode, to be externally connected to V_{CC} through a current control resistor. This pin is allowed to be supplied from an uncontrolled power supply separated from the controlled V_{CC} supply		
2	1	IRED Cathode	IRED cathode, internally connected to driver transistor		
3	7	Txd	Transmit Data Input	I	HIGH
4	2	Rxd	Received Data Output, push-pull CMOS driver output capable of driving a standard CMOS or TTL load. No external pull-up or pull-down resistor is required. Pin is switched to ground when device is in shutdown mode	0	LOW
5	6	SD/Mode	Shutdown/ Mode	I	HIGH
6	3	V _{CC}	Supply Voltage		
7	5	Mode	HIGH: High speed mode; LOW: Low speed mode, SIR only (see chapter "Mode Switching")	I	
8	4	GND	Ground		

"U" Option Baby Face (Universal) and Dracula



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"S" Option Side View

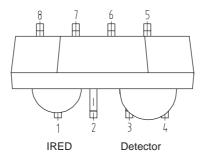
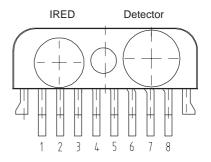


Figure 2. Pinnings

"T" Option Top View







Absolute Maximum Ratings

Reference point Pin: GND unless otherwise noted.

Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.

Parameters	Test Conditions	Symbol	Min.	Тур.	Max.	Unit
Supply Voltage Range, Transceiver	0 V <v<sub>CC2 <6 V</v<sub>	V _{CC1}	- 0.5		6	V
Supply Voltage Range, Transmitter	0 V <v<sub>CC1 <6 V</v<sub>	V _{CC2}	- 0.5		6	V
Input Currents	For all Pins, Except IRED Anode Pin				10	mA
Output Sinking Current					25	mA
Power Dissipation	See Derating Curve	P _D			350	mW
Junction Temperature		T_J			125	°C
Ambient Temperature Range (Operating)		T _{amb}	-25		+85	°C
Storage Temperature Range		T _{stg}	-25		+85	°C
Soldering Temperature	See Recommended Solder Profile (see Figure 11)				240	°C
Average Output Current		I _{IRED} (DC)			130	mA
Repetitive Pulsed Output Current	<90 μs, t _{on} <20%	I _{IRED} (RP)			600	mA
IRED Anode Voltage		V _{IREDA}	- 0.5		6	V
Transmitter Data Input Voltage		V _{Txd}	- 0.5		V _{CC1} +0.5	V
Receiver Data Output Voltage		V _{Rxd}	- 0.5		V _{CC1} +0.5	V
Virtual Source Size	Method: (1–1/e) encircled energy	d	2.5	2.8		mm
Maximum Intensity for Class 1 Operation of IEC825–1 or EN60825–1 (worst case IrDA FIR pulse pattern)	EN60825, 1997, unidirectional operation, worst case test mode				320	mW/sr



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Electrical Characteristics

 T_{amb} = 25°C, V_{CC} = 2.6V to 5.5 V unless otherwise noted. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.

Parameters	Test Conditions / Pins	Symbol	Min.	Тур.	Max.	Unit		
Transceiver								
Supply Voltage		V _{CC}	2.6		5.5	V		
Dynamic Supply Current	Receive mode only. In transmit mode, add additional 85 mA (typ) for IRED current							
	$SD = Low, E_e = 0 klx$	Icc		3	4.5	mA		
	$SD = Low, E_e = 1 klx *)$	I _{CC}		3	4.5	mA		
Standby Supply Current	SD = High, Mode = Floating, $T = 25^{\circ}C, E_e = 0 klx$ $T = 25^{\circ}C, E_e = 1 klx *)$	I _{SD}			1 1.5	μΑ μΑ		
	SD = High, T = 85°C, Mode = Floating, Not Ambient Light Sensitive	I _{SD}			5	μΑ		
Operating Temperature Range		T _A	-25		+85	°C		
Output Voltage Low	$R_{load} = 2.2 \text{ k}\Omega,$ $C_{load} = 15 \text{ pF}$	V _{OL}		0.5	0.8	V		
Output Voltage High	$R_{load} = 2.2 \text{ k}\Omega,$ $C_{load} = 15 \text{ pF}$	V _{OH}	V _{CC} -0.5			V		
Input Voltage Low (Txd, SD/ Mode, Mode)		V _{IL}	0		0.8	V		
Input Voltage High	CMOS level **)	V _{IH}	0.9 x V _{CC}			V		
(Txd, SD/ Mode, Mode)	TTL level, V _{CC} ≥ 4.5 V	V _{IH}	2.4			V		
Input Leakage Current (Txd, SD/ Mode)		IL	-10		+10	μА		
Input Leakage Current, Mode		ΙL	-80		+80	μА		
Input Capacitance		C _I			5	pF		

^{*)} Standard Illuminant A

^{**)} The typical threshold level is between $0.5 \times V_{CC/2}$ ($V_{CC} = 3 \text{ V}$) and $0.4 \times V_{CC}$ ($V_{CC} = 5.5 \text{ V}$). It is recommended to use the specified min/ max values to avoid increased operating current.

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Optoelectronic Characteristics

 T_{amb} = 25°C, V_{CC} = 2.6 V to 5.5 V unless otherwise noted. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.

Parameters	Test Conditions	Symbol	Min.	Тур.	Max.	Unit
Receiver						
Minimum Detection Threshold Irradiance, SIR Mode	TFDS6501E/ TFDT6501E 9.6 kbit/s to 115.2 kbit/s λ = 850 nm to 900 nm	E _e		20	35	mW/m ²
	TFDU6101E, TFDS6401 9.6 kbit/s to 115.2 kbit/s λ = 850 nm to 900 nm	E _e		25	40	mW/m ²
Minimum Detection Threshold Irradiance, MIR Mode	TFDS6501E/ TFDT6501E 1.152 Mbit/s λ = 850 nm to 900 nm	E _e		50		mW/m ²
	TFDU6101E, TFDS6401 1.152 Mbit/s λ = 850 nm to 900 nm	E _e		65		mW/m ²
Minimum Detection Threshold Irradiance, FIR Mode	TFDS6501E/ TFDT6501E 4.0 Mbit/s λ = 850 nm to 900 nm	E _e		65	100	mW/m ²
	TFDU6101E, TFDS6401 4.0 Mbit/s λ = 850 nm to 900 nm	E _e		85	100	mW/m ²
Maximum Detection Threshold Irradiance	$\lambda = 850 \text{ nm to } 900 \text{ nm}$	E _e	5	10		kW/m ²
Logic LOW Receiver Input Irradiance		E _e	4			mW/m ²
Rise Time of Output Signal—,,,,klll	10% to 90%, @2.2 kΩ, 15 pF	t _{r (Rxd)}	10		40	ns
Fall Time of Output Signal	90% to 10%, @2.2 kΩ, 15 pF	t _{f (Rxd)}	10		40	ns
Rxd Pulse Width of	Input pulse length 20 μs, 9.6 kbit/s	t _{PW}	1.2	10	20	μs
Output Signal, 50% SIR Mode	Input pulse length 1.41 μs, 115.2 kbit/s	t _{PW}	1.2		1/2 bit length	μs
Rxd Pulse Width of Output Signal, 50% MIR Mode	Input pulse length 217 ns, 1.152 Mbit/s	t _{PW}	110		260	ns
Rxd Pulse Width of	Input pulse length 125 ns, 4.0 Mbit/s	t _{PW}	100		160	ns
Output Signal, 50% FIR Mode	Input pulse length 250 ns, 4.0 Mbit/s	t _{PW}	200		290	ns
Stochastic Jitter, Leading Edge, FIR Mode	Input Irradiance = 100 mW/m ² , 4.0 Mbit/s			±10		ns
Latency		tL		120	300	μs



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Optoelectronic Characteristics (continued)

 T_{amb} = 25°C, V_{CC} = 2.6 V to 5.5 V unless otherwise noted. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.

Parameters	Test Conditions	Symbol	Min.	Тур.	Max.	Unit
Transmitter						
IRED Operating Current	$R1^*$) = 7.2 Ω , V_{CC} = 5.0 V	I_{D}		0.4	0.55	А
Output Radiant Intensity (see Figure 3)	V_{CC} = 5.0 V, α = 0°, 15° Txd = High, SD = Low, R1 = 7.2 Ω	l _e	120	170	350	mW/sr
Output Radiant Intensity	V_{CC} = 5.0 V, α = 0°, 15° Txd = Low, SD = High, (Receiver is inactive as long as SD = High) R1 = 7.2 Ω	l _e			0.04	mW/sr
Output Radiant Intensity, Angle of Half Intensity		α		±24		0
Peak – Emission Wavelength		$\lambda_{ m P}$	880		900	nm
Optical Output Pulse Duration	Input pulse width 217 ns, 1.152 Mbit/s	t _{opt}	207	217	227	ns
	Input pulse width 125 ns, 4 Mbit/s	t _{opt}	117	125	133	ns
	Input pulse width 250 ns, 4 Mbit/s	t _{opt}	242	250	258	ns
	Input pulse width t < 80 μ s Input pulse width t \geq 80 μ s	t _{opt}		t	80	μs
Optical Rise Time, Fall Time		t _{ropt} , t _{fopt}	10		40	ns
Optical Overshoot					10	%

*) R1: control series resistor for current limitation

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Recommended Circuit Diagram

The only required component for designing an IrDA 1.3 solution using Vishay Telefunken transceivers is a current limiting resistor, R1, to the IRED. However, depending on the entire system design and board layout, additional components may be required (see figure KEIN MERKER).

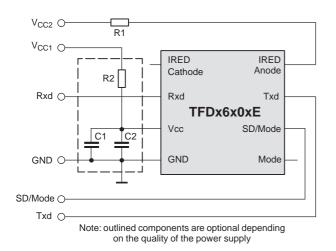


Figure 3. Recommended Application Circuit

Vishay Telefunken transceivers integrate a sensitive receiver and a built-in power driver. The combination of both needs a careful circuit board layout. The use of thin, long, resistive and inductive wiring should be avoided. The inputs (Txd, SD/ Mode) and the output Rxd should be directly (DC) coupled to the I/O circuit.

R1 is used for controlling the current through the IR emitter. For increasing the output power of the IRED, the value of the resistor should be reduced. Similarly, to reduce the output power of the IRED, the value of the resistor should be increased. For typical values of R1 see figure 4. For IrDA compliant operation, a current control resistor of 7.2 Ω is recommended. For compensating losses of the cosmetic window, reducing that value to 5.6 Ω is acceptable. The upper drive current limitation is dependent on the duty cycle and is given by the absolute maximum ratings on the data sheet.

R2, C1 and C2 are optional and dependent on the quality of the supply voltage V_{CC} and injected noise. An unstable power supply with dropping voltage during transmission may reduce sensitivity (and transmission range) of the transceiver.

The placement of these parts is critical. It is strongly recommended to position C2 as near as possible to the transceiver power supply pins. An electrolytic capacitor should be used for C1 while a ceramic capacitor is used for C2.

Table 1. Recommended Application Circuit Components

Component	Recommended Value	Vishay Part Number
C1	4.7 μF, Tantalum	293D 475X9 016B 2T
C2	0.1 μF, Ceramic	VJ 1206 Y 104 J XXMT
R1	5 V supply voltage: 7.2 Ω , 0.25 W (recommend using two 3.6 Ω , 0.125 W resistors in series) 3.3 V supply voltage: 3.6 Ω , 0.25 W (recommend using two 1.8 Ω , 0.125 W resistors in series)	CRCW-1206-3R60-F-RT1 CRCW-1206-1R80-F-RT1
	,	
R2	47 Ω , 0.125 W	CRCW-1206-47R0-F-RT1

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TFDU6101E/TFDS6401/TFDS6501E/TFDT6501E

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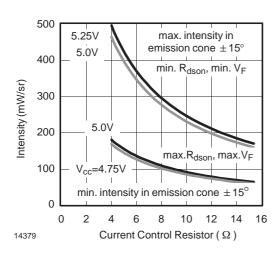


Figure 4. Intensity I_e vs. Current Control Resistor R1, 5 V Applications

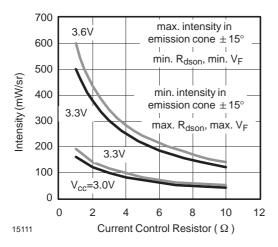


Figure 5. Intensity I_e vs. Current Control Resistor R1, 3 V Applications

In addition, when connecting the described circuit to the power supply, low impedance wiring should be used.

I/O and Software

In the description, already different I/Os are mentioned. Differnt combinations are tested and the function verified with the special drivers available from the I/O suppliers. In special cases refer to the I/O manual, the Vishay application notes, or contact directly Vishay Sales, Marketing or Application.

Control: Differences to TFDx6000 Series

For applications using I/Os from NSC, Winbond and TI no software upgrade is necessary. In combination with the latest SMSC controllers for Microsoft Windows $98^{\$}$ a software upgrade is necessary,

drivers are available from SMSC and Vishay Semiconductor GmbH. This software is intended to work with Windows 95[®], too. Alternatively the HP/ Sharp settings can be selected. The Microsoft Operating Systems NT 5.0[®] Beta 2 and Windows 2000[®] provide Miniport device drivers.

Mode Switching

The TFDU6101E, TFDS6401, TFDS6501E and TFDT6501E do not power on with a default mode, therefore the data transfer rate has to be set by a programming sequence using the Txd and SD/ Mode inputs as described below or selected by setting the Mode Pin. The Mode Pin can be used to statically set the mode (Mode Pin: LOW: SIR, HIGH: 0.576 Mbit/s to 4.0 Mbit/s). When using the Mode Pin, the standby current may increase to about 50 to 60 µA when high or low. If not used or in standby mode, the mode input should float to minimize standby current. The low frequency mode covers speeds up to 115.2 kbit/s. Signals with higher data rates should be detected in the high frequency mode. Lower frequency data can also be received in the high frequency mode but with reduced sensitivity. To switch the transceivers from low frequency mode to the high frequency mode and vice versa, the programming sequences described below are required.

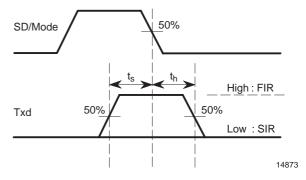


Figure 6. Mode Switching Timing Diagram

Setting to the High Bandwidth Mode (0.576 Mbit/s to 4.0 Mbit/s)

- 1. Set SD/MODE input to logic "HIGH".
- 2. Set Txd input to logic "HIGH". Wait $t_s \ge 200$ ns.
- Set SD/MODE to logic "LOW" (this negative edge latches state of Txd, which determines speed setting).
- After waiting t_h ≥ 200 ns Txd can be set to logic "LOW". The hold time of Txd is limited by the maximum allowed pulse length.

Txd is now enabled as normal Txd input for the high bandwidth mode.

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Setting to the Lower Bandwidth Mode (2.4 kbit/s to 115.2 kbit/s)

- 1. Set SD/MODE input to logic "HIGH".
- 2. Set Txd input to logic "LOW". Wait $t_s \ge 200$ ns.
- Set SD/MODE to logic "LOW" (this negative edge latches state of Txd, which determines speed setting).
- 4. Txd must be held for $t_h \ge 200$ ns.

Txd is now enabled as normal Txd input for the lower bandwidth mode.

Recommended SMD Pad Layout

The leads of the device should be soldered in the center position of the pads.

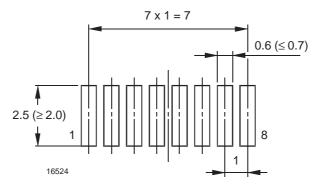


Figure 7. TFDU6101E BabyFace (Universal)

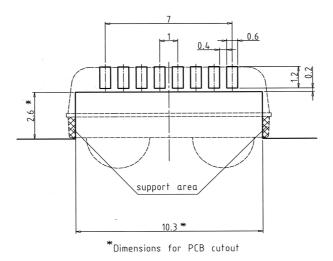


Figure 8. TFDS6401 (Dracula)

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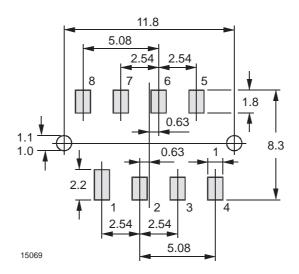


Figure 9. TFDS6501E Side View Package Pad 1 is longer to designate Pin 1 connection to transceiver.

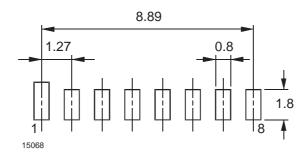


Figure 10. TFDT6501E Top View Package Pad 1 is longer to designate Pin 1 connection to transceiver.

Note: Leads of the device should be at least 0.3 mm within the ends of the pads.

Recommended Solder Profile

240 10 s max. @ 230°C 210 2 - 4°C/s Temperature (°C) 180 150 120 120 - 180 s 90 s max 90 60 30 350 0 50 100 150 200 250 300 Time (s) 14874

Figure 11. Recommended Solder Profile

Current Derating Diagram

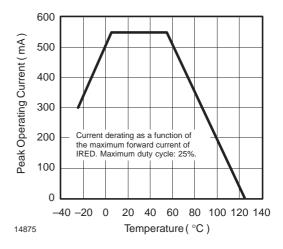
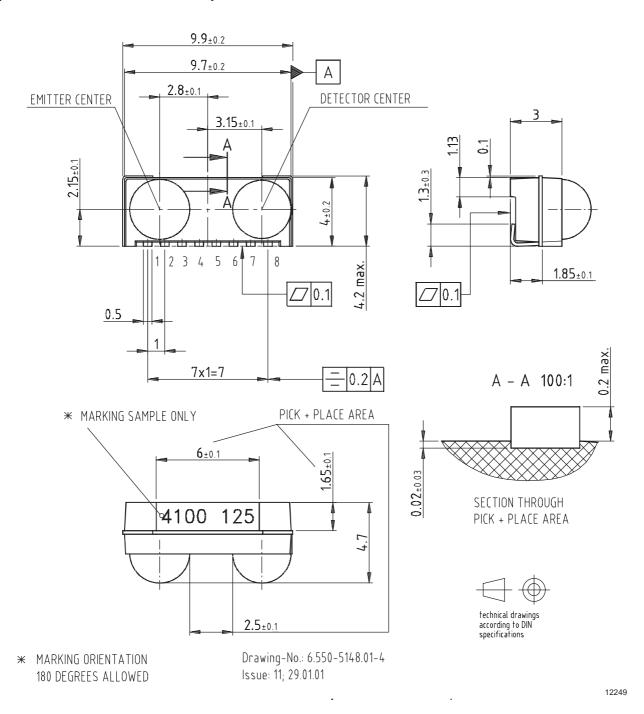


Figure 12. Current Derating Diagram

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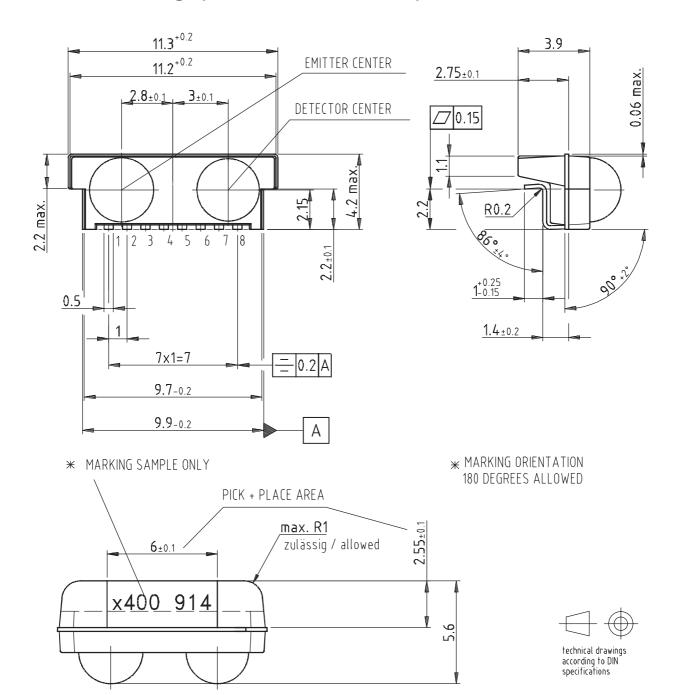
TFDU6101E – Baby Face (Universal) Package (Mechanical Dimensions)





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TFDS6401 Package (Mechanical Dimensions)



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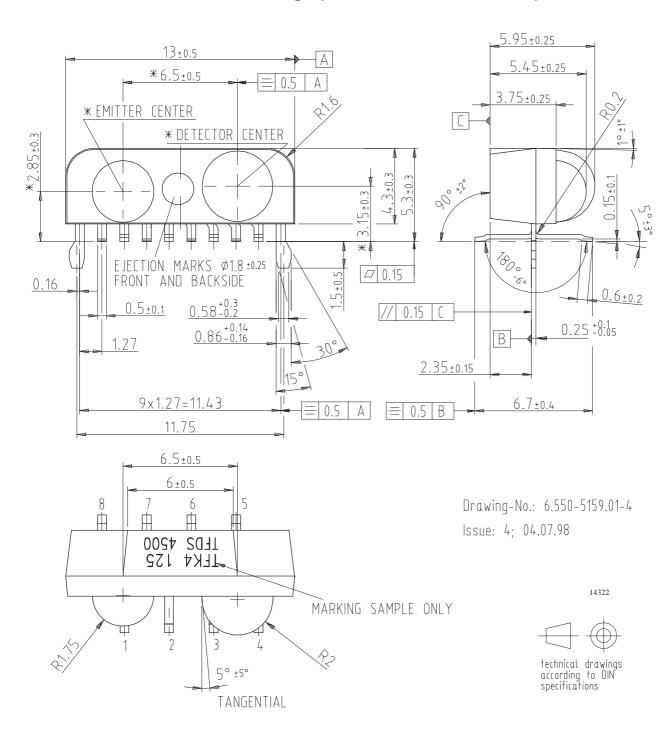
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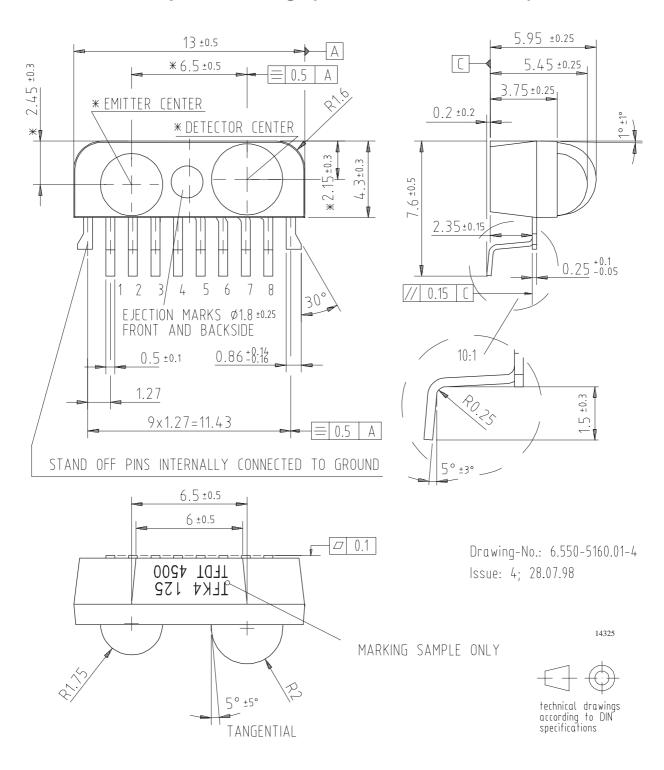
TFDS6501E – Side View Package (Mechanical Dimensions)





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TFDT6501E – Top View Package (Mechanical Dimensions)



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Revision History:

B1.1, 01/03/1999: New edition for optimized E family. TFDxxx01E – RXD output is grounded when the device

is switched to shutdown mode.

B1.2, 15/03/1999: A clean tri-state version with floating output in shutdown mode was added as 02 version. The

output radiant intensity was increased.

B1.4a, 26/10/1999:TR3 changed to TR4 for 01 types, weight of packages added.

B1.4b, 22/11/1999: Max. operating current changed from 4.0 mA to 4.5 mA, Dracula package version added,

some typos corrected.

B1.5, 13/10/2000: Typos corrected

B1.6, 02/11/2000: SMD pad layout tolerances added



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Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice. Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Telefunken products for any unintended or unauthorized application, the buyer shall indemnify Vishay Telefunken against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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